BT300 series

GENERAL DESCRIPTION

Glass passivated thyristors in a plastic envelope, intended for use in applications requiring high bidirectional blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

PINNING - TO220AB

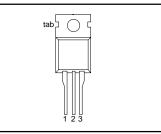
QUICK REFERENCE DATA

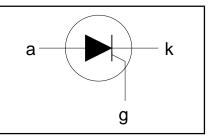
| SYMBOL | PARAMETER | MAX. | MAX. | MAX. | UNIT |
|---|--|------------------------------------|------------------------------------|------------------------------------|------------------|
| V _{drm} , V _{rrm} I _{t(av)} I _{t(rms)} I _{tsm} | BT300- Repetitive peak off-state voltages Average on-state current RMS on-state current Non-repetitive peak on-state current | 500R 500 5 8 65 | 600R 600 5 8 65 | 800R 800 5 8 65 | V A A A |

PIN CONFIGURATION

SYMBOL

| PIN | PIN DESCRIPTION | |
|-----|-----------------|--|
| 1 | cathode | |
| 2 | anode | |
| 3 | gate | |
| tab | anode | |





LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | | MAX. | | UNIT |
|---|---|---|----------|----------------------------------|----------------------------------|---------------------|------------------|
| V_{drm}, V_{rrm} | Repetitive peak off-state voltages | | - | -500R 500 ¹ | -600R 600 ¹ | -800R 800 | V |
| I _{T(AV)} I _{T(RMS)} I _{TSM} | Average on-state current RMS on-state current Non-repetitive peak on-state current | half sine wave; $T_{mb} \le 111$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge | - | 5 8 | | A A | |
| | | t = 10 ms t = 8.3 ms | - | | 65 71 | | A A |
| l ² t | I ² t for fusing | t = 10 ms | - | | 21 | | A ² s |
| dl _T /dt | Repetitive rate of rise of on-state current after triggering | $I_{TM} = 10 \text{ A}; I_G = 50 \text{ mA}; dI_G/dt = 50 \text{ mA/}\mu s$ | - | | 50 | | A/μs |
| IGM | Peak gate current | | - | | 2 | | Α |
| I _{GM} V _{GM} | Peak gate voltage | | - | | 2 5 5 | | V |
| V _{RGM} | Peak reverse gate voltage | | - | | 5 | | V |
| P _{GM} | Peak gate power | | - | | 5 | | W |
| P _{G(AV)} T _{stg} T _j | Average gate power Storage temperature Operating junction temperature | over any 20 ms period | -40 - | | 0.5 150 125 | | ວໍລິ≜ |

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.

BT300 series

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------|--|-------------|------|------|------|------|
| R _{th j-mb} | Thermal resistance junction to mounting base | | - | - | 1.8 | K/W |
| R _{th j-a} | Thermal resistance junction to ambient | in free air | - | 60 | - | K/W |

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|---------------------------|--|------|------|------|------|
| I _{GT} | Gate trigger current | $V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$ | - | 2 | 15 | mA |
| | Latching current | $V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$ | - | 10 | 40 | mA |
| | Holding current | $V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$ | - | 10 | 20 | mA |
| V _τ | On-state voltage | $I_{T} = 12 \text{ A}$ | - | 1.35 | 1.6 | V |
| V _{GT} | Gate trigger voltage | $\dot{V}_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$ | - | 0.6 | 1.5 | V |
| | | $V_{\rm D} = V_{\rm DRM(max)}$; $I_{\rm T} = 0.1$ A; $T_{\rm i} = 125$ °C | 0.25 | 0.4 | - | V |
| I _D , I _R | Off-state leakage current | $V_D = V_{DRM(max)}^{DRM(max)}; V_R = V_{RRM(max)}; T_j = 125 \text{°C}$ | - | 0.1 | 0.5 | mA |

DYNAMIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---------------------|--|--|------|------|------|------|
| dV _D /dt | Critical rate of rise of off-state voltage | $V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform. | | | | |
| | | Gate open circuit | 50 | 100 | - | V/µs |
| | | $R_{GK} = 100 \Omega$ | 200 | 1000 | - | V/µs |
| t _{gt} | Gate controlled turn-on time | $I_{TM} = 10 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu \text{s}$ | - | 2 | - | μs |
| t _q | Circuit commutated turn-off time | | - | 70 | - | μs |

BT300 series

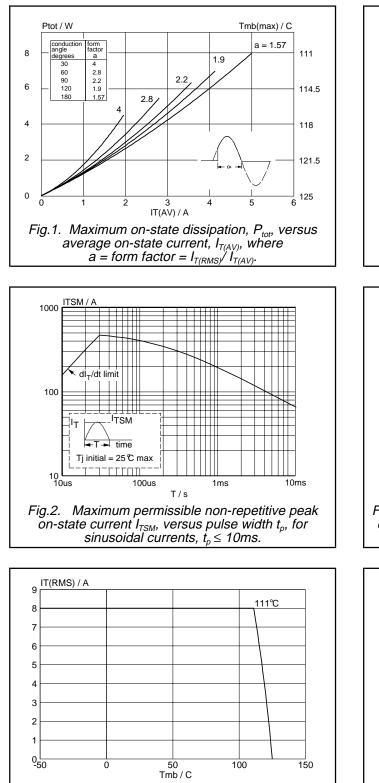
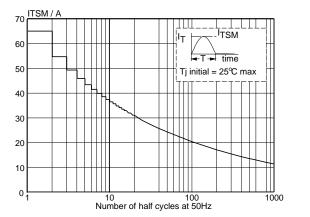
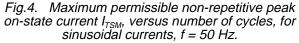


Fig.3. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .





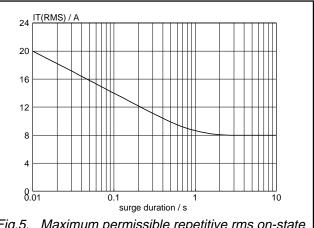
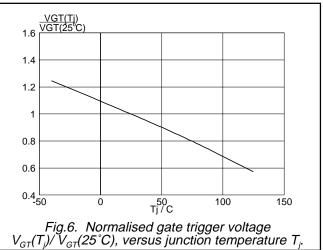


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 111$ °C.



BT300 series

max

2

typ

1.5

0.1s

1s

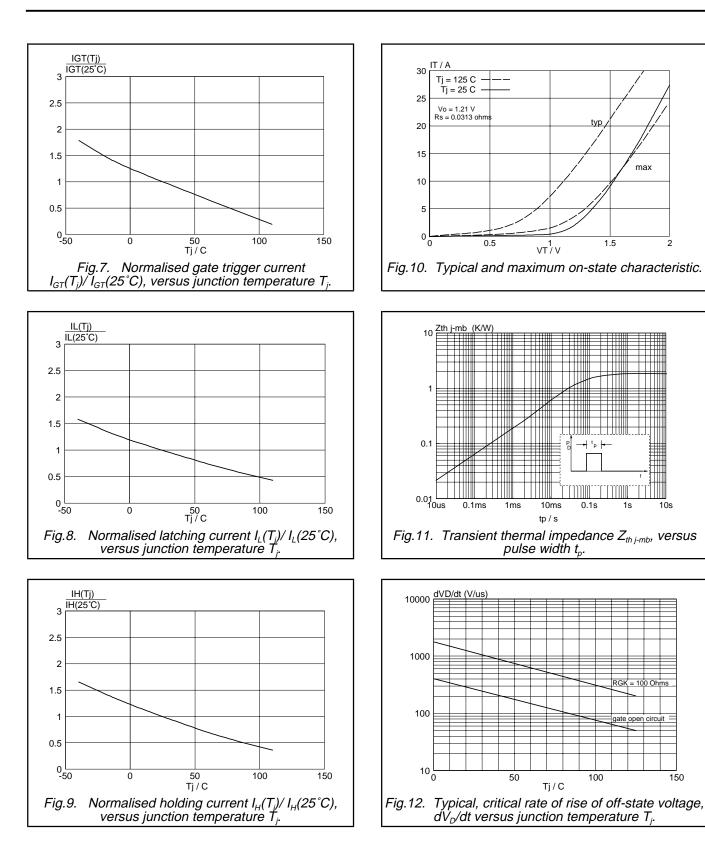
RGK = 100 Ohms

ate open circuit

100

Tj / C

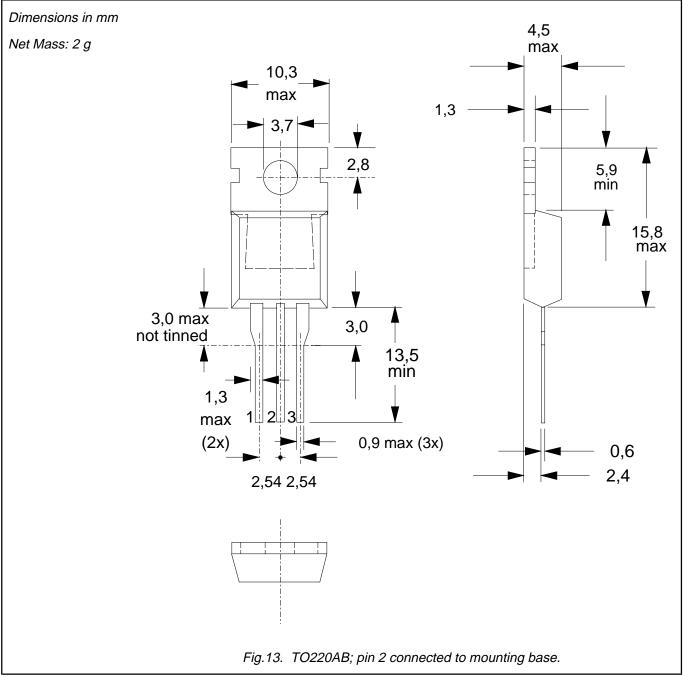
10s



150

BT300 series

MECHANICAL DATA



Notes 1. Refer to mounting instructions for TO220 envelopes. 2. Epoxy meets UL94 V0 at 1/8".

DEFINITIONS

| Data sheet status | | | | | |
|--|---|--|--|--|--|
| Objective specification This data sheet contains target or goal specifications for product development. | | | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | | | | |
| Product specification | This data sheet contains final product specifications. | | | | |
| Limiting values | | | | | |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | | | |
| Application information | | | | | |
| Where application information is given, it is advisory and does not form part of the specification. | | | | | |
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